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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORVEN	
09/943,383	08/31/2001		ATTORNEY DOCKET NO.	CONFIRMATION N
		Arulkumar P. Shanmugasundram	5920/FET/DV	7797
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APPLIED MATERIALS, INC.			EXAMINER	
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•	*	,	2823	
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Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	- yr
Office Action Summary	09/943,383	SHANMUGASUND	RAM ET AI
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The MAN INC DATE	W. David Coleman	] .	
The MAILING DATE of this communication Period for Reply	app ars on the cover she t with	the correspond nce add	ress
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION  Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  If the period for reply specified above is less than thirty (30) days, a length of the period for reply is specified above, the maximum statutory perions from the period for reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the material patent term adjustment. See 37 CFR 1.704(b).  Status  1) Responsive to communication(s) filed on 20	PLY IS SET TO EXPIRE 3 MO N.  1.136(a). In no event, however, may a reply within the statutory minimum of thirty (3 lod will apply and will expire SIX (6) MONTH tute, cause the application to become ABAN ailing date of this communication, even if time 1.1 May 2004.  May 2004.  his action is non-final.	NTH(S) FROM  by be timely filed  30) days will be considered timely.  S from the mailing date of this coming the second state of the second state	munication.
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4) Claim(s) <u>1-72</u> is/are pending in the application	on.		
4a) Of the above claim(s) <u>55-72</u> is/are withdra	awn from consideration.		
s) Claim(s) is/are allowed.			•
6)⊠ Claim(s) <u>1-54</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.	•	
pplication Papers	·		٠.
9) The specification is objected to by the Examin			
10) The drawing(s) filed on island and			
10) The drawing(s) filed on is/are: a) acc	cepted or b) diected to by the	he Examiner.	
Applicant may not request that any objection to the	e drawing(s) be held in abeyance.	See 37 CFR 1.85(a).	
including the correct	tion is required if the description ( )	a a constant of the constant o	.121(d)
and the objected to by the E	xaminer. Note the attached Off	ice Action or form PTO-1	52.
riority under 35 U.S.C. § 119			-
12) Acknowledgment is made of a claim for foreign	nriority under 25 U.O.O. A. 445	M-N ( D )	
a) ☐ All b) ☐ Some * c) ☐ None of:	. Priority under 35 U.S.C. § 119	v(a)-(d) or (f).	•
1. Certified copies of the priority document	s have hoon manifes it	$\label{eq:definition} (A, A, A$	
2. Certified copies of the priority document	s have been received.		*
<ul><li>2. ☐ Certified copies of the priority document</li><li>3. ☐ Copies of the certified copies of the priority</li></ul>	strate been received in Applic	ation No	
3. Copies of the certified copies of the prior	incy documents have been rece	ived in this National Stag	ė.
approaution the international Bilibar	1 (PCT Rule 17.9/a))		
* See the attached detailed Office action for a list	or the certified copies not recei	ved.	
achment(s)			
Notice of References Cited (PTO-892)			
☐ Notice of Draftsperson's Patent Drawing Poview (DTO 040)	4) Interview Summa	ry (PTO-413)	
オ・。 Taken Drawing Review (P1U-948)	Paper No(s)/Mail	Date.	
Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date <u>various</u> .	5) Notice of Informal	Patent Application (PTO-152)	

Art Unit: 2823

## Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.
- 2. The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).
- 3. Claims 1-54 are rejected under 35 U.S.C. 102(e) as being anticipated by Miller et al., U.S. Patent 6,197,604 B1.

Miller discloses a semiconductor process as claimed. See FIGS. 1-9 where Miller teaches the claimed invention.

- 4. Pertaining to claim 1, Miller teaches a method for controlling a wafer property in a semiconductor processing tool using data collected from an in situ sensor, said method comprising the steps of:
- (1) setting recipe parameters relating to said wafer property according to a process model, wherein said model is used to predict wafer outputs (box 110 in FIG. 1);
- (2) executing a process (box 102) on a wafer with the tool according to said recipe parameters;

Art Unit: 2823

(3) collecting data (see FIG. 7) relating to said wafer property during execution of said process with said in situ sensor,

- (4) adjusting said process by modifying said recipe parameters according to comparisons between said data collected by said in situ sensor relating to said wafer property and results predicted by said model; and
- (5) using said data collected by said in situ sensor in a process on a subsequent wafer to be executed by the tool (see FIG. 9 also this is well known as a run-to-run process).
- 5. Pertaining to claim 2, Miller teaches the method of claim 1, wherein said property comprises wafer thickness due to a CMP (chemical-mechanical polish process the thickness of the wafer will change).
- 6. Pertaining to claim 3, Miller teaches the method of claim 1, wherein said tool comprises a polishing device.
- 7. Pertaining to claim 4, Miller teaches the method of claim 1, wherein said tool comprises a plurality of processing resources, each of which includes an in situ sensor, and wherein data from one in situ sensor may be forwarded to another processing resource in real time during execution of said process (box 904).
- 8. Pertaining to claim 5, Miller teaches the method of claim 1, further comprising the step of collecting data from an inline sensor; and integrating said data collected from said inline sensor with said data collected from said in situ sensor before processing said subsequent wafer (hence, run-to-run process).
- 9. Pertaining to claim 6, Miller teaches the method of claim 5, wherein data collected from said inline sensor is utilized to calibrate said in situ sensor (box 902).

Art Unit: 2823

- 10. Pertaining to claim 7, Miller teaches the method of claim 1, further comprising the step of collecting data from a sensor located at an upstream tool; and integrating said data collected from said upstream tool with said data collected from said in situ sensor before processing said subsequent wafer (box 910/912).
- 11. Pertaining to claim 8, <u>Miller</u> teaches the method of claim 7, wherein data collected from said upstream tool is utilized to calibrate said in situ sensor.
- 12. Pertaining to claim 9, Miller teaches the method of claim 1, wherein said parameters include a processing time (column 11, line 58).
- 13. Pertaining to claim 10, <u>Miller</u> teaches the method of claim 1, wherein said data collected by said in situ sensor is used for run- to-run control on subsequent wafers processed by said tool.
- 14. Pertaining to claim 11, Miller teaches the method of claim 1, wherein said tool comprises a plurality of processing devices, each of which includes an in situ sensor, and wherein data from one in situ sensor may be compared with data from another in situ sensor to in real time to compare results from each device.
- 15. Pertaining to claim 12, <u>Miller</u> teaches a method for controlling a wafer property in a semiconductor processing tool using data collected from an in situ sensor, said method comprising the steps of:
- (1) collecting data with said in situ sensor relating to said wafer property during a process executed according to wafer recipe parameters;

Art Unit: 2823

- (2) adjusting said process by modifying said recipe parameters according to comparisons between said data collected by said in situ sensor relating to said wafer property and results predicted by a process model used to predict wafer outputs; and
- (3) using said data collected by said in situ sensor in a process on a subsequent wafer to be executed by the tool.
- 16. Pertaining to claim 13, <u>Miller</u> teaches the method of claim 12, wherein said step of adjusting comprises increasing or decreasing a processing time.
- 17. Pertaining to claim 14, <u>Miller</u> teaches the method of claim 13, wherein said processing time comprises polishing time.
- 18. Pertaining to claim 15, Miller teaches the method of claim 12, wherein said tool comprises a plurality of processing resources, each of which includes an in situ sensor, and wherein data from one in situ sensor may be forwarded to another processing resource in real time during execution of said process.
- 19. Pertaining to claim 16, Miller teaches the method of claim 12, further comprising the step of collecting data from an inline sensor, and integrating said data collected from said inline sensor with said data collected from said in situ sensor before processing said subsequent wafer.
- 20. Pertaining to claim 17, Miller teaches the method of claim 12, further comprising the step of collecting data from a sensor located at an upstream tool, and integrating said data collected from said upstream tool with said data collected from said in situ sensor before processing said subsequent wafer.

Art Unit: 2823

21. Pertaining to claim 18, Miller teaches the method of claim 12, wherein said data collected by said in situ sensor is used for run-to-run control on subsequent wafers processed by said tool.

22. Pertaining to claim 19, <u>Miller</u> teaches a system for controlling a wafer property comprising:

a semiconductor processing tool capable of executing a process for processing a wafer according to recipe parameters relating to a wafer property;

an in situ sensor configured to collect data relating to said wafer property during execution of said process; and

a processor useable for setting said recipe parameters according to a process model for predicting wafer outputs, wherein said processor is utilizable for adjusting said process by modifying said recipe parameters according to comparisons between said data collected by said in situ sensor relating to said wafer property and results predicted by said model, and wherein said processor uses said data collected by said in situ sensor in a process on a subsequent wafer to be executed by the tool.

- 23. Pertaining to claim 20, <u>Miller</u> teaches the system of claim 19, wherein said wafer property comprises wafer thickness.
- 24. Pertaining to claim 21, <u>Miller</u> teaches the system of claim 19, wherein said tool comprises a polishing device.
- 25. Pertaining to claim 22, Miller teaches the system of claim 19, wherein said tool comprises a plurality of processing resources, each of which includes an in situ sensor, and wherein data from one in situ sensor may be forwarded to another processing resource in real time during execution of said process.

Art Unit: 2823

26. Pertaining to claim 23, Miller teaches the system of claim 19, further comprising an inline sensor configured to collect data, wherein said data collected from said inline sensor is integrated with said data collected from said in situ sensor before processing said subsequent wafer.

- 27. Pertaining to claim 24, <u>Miller</u> teaches the system of claim 23, wherein data collected from said inline sensor is utilized to calibrate said in situ sensor.
- Pertaining to claim 25, Miller teaches the system of claim 19, further comprising a sensor located at an upstream tool configured to collect data, wherein said data collected from said upstream tool is integrated with said data collected from said in situ sensor before processing said subsequent wafer.
- 29. Pertaining to claim 26, Miller teaches the system of claim 25, wherein data collected from said upstream tool is utilized to calibrate said in situ sensor.
- 30. Pertaining to claim 27, <u>Miller</u> teaches the system of claim 19, wherein said parameters include a processing time.
- Pertaining to claim 28, Miller teaches the system of claim 19, wherein said data collected by said in situ sensor is used for run-to-run control on subsequent wafers processed by said tool.
- 32. Pertaining to claim 29, Miller teaches the system of claim 19, wherein said tool comprises a plurality of processing devices, each of which includes an in situ sensor, and wherein data from one in situ sensor may be compared with data from another in situ sensor to in real time to compare results from each device.
- 33. Pertaining to claim 30, <u>Miller</u> teaches a system for controlling a wafer property comprising:

Art Unit: 2823

an in situ sensor for collecting data relating to said wafer property during a process executed by a semiconductor processing tool according to wafer recipe parameters;

a processor configured to adjust said process by modifying said recipe parameters according to comparisons between said data collected by said in situ sensor relating to said wafer property and results predicted by a process model used to predict wafer outputs; and wherein said processor is configured to use said data collected by said in situ sensor in a process on a subsequent wafer to be executed by the tool

- 34. Pertaining to claim 31, <u>Miller</u> teaches the system of claim 30, wherein said processor is configured to increase or decrease a processing time of the tool.
- 35. Pertaining to claim 32, <u>Miller</u> teaches the system of claim 31, wherein said processing time comprises polishing time.
- 36. Pertaining to claim 33, <u>Miller</u> teaches the system of claim 30, wherein said tool comprises a plurality of processing resources, each of which includes an in situ sensor, and wherein data from one in situ sensor may be forwarded to another processing resource in real time during execution of said process.
- 37. Pertaining to claim 34, Miller teaches the system of claim 30, further comprising an inline sensor configured to collect data, and wherein said inline sensor is adapted to integrate said collected data with said data collected from said in situ sensor before processing said subsequent wafer.
- Pertaining to claim 35, Miller teaches the system of claim 30, further comprising a sensor located at an upstream tool configured to collect data, and wherein said sensor is adapted to

Art Unit: 2823

integrate said collected data with said data collected from said in situ sensor before processing said subsequent wafer.

- 39. Pertaining to claim 36, <u>Miller</u> teaches the system of claim 30, wherein said data collected by said in situ sensor is used for run-to-run control on subsequent wafers processed by said tool.
- 40. Pertaining to claim 37, <u>Miller</u> teaches a system for controlling a wafer property in a semiconductor processing tool using data collected from an in situ sensor, said system comprising:

means for setting recipe parameters relating to said wafer property according to a process model, wherein said model is used to predict wafer outputs;

means for executing a process on a wafer with the tool according to said recipe parameters; means for collecting data relating to said wafer property during execution of said process with said in situ sensor;

means for adjusting said process by modifying said recipe parameters according to comparisons between said data collected by said in situ sensor relating to said wafer property and results predicted by said model; and

means for using use said data collected by said in situ sensor in a process on a subsequent wafer to be executed by the tool.

- Pertaining to claim 38, <u>Miller</u> teaches the system of claim 37, wherein said property comprises wafer thickness.
- 42. Pertaining to claim 39, <u>Miller</u> teaches the system of claim 37, wherein said tool comprises a polishing device.

Art Unit: 2823

- 43. Pertaining to claim 40, <u>Miller</u> teaches the system of claim 37, wherein said tool comprises a plurality of processing resources, each of which includes an in situ sensor, and wherein data from one in situ sensor may be forwarded to another processing resource in real time during execution of said process.
- 44. Pertaining to claim 41, Miller teaches the system of claim 37, further comprising means for collecting data from an inline sensor; and means for integrating said data collected from said inline sensor with said data collected from said in situ sensor before processing said subsequent wafer.
- Pertaining to claim 42, <u>Miller</u> teaches the system of claim 41, wherein data collected from said inline sensor is utilized to calibrate said in situ sensor.
- 46. Pertaining to claim 43, Miller teaches the system of claim 37, further comprising means for collecting data from a sensor located at an upstream tool; and means for integrating said data collected from said upstream tool with said data collected from said in situ sensor before processing said subsequent wafer.
- Pertaining to claim 44, <u>Miller</u> teaches the system of claim 43, wherein data collected from said upstream tool is utilized to calibrate said in situ sensor.
- 48. Pertaining to claim 45, <u>Miller</u> teaches the system of claim 37, wherein said parameters include a processing time.
- 49. Pertaining to claim 46, <u>Miller</u> teaches the system of claim 37, wherein said data collected by said in situ sensor is used for run-to-run control on subsequent wafers processed by said tool.
- 50. Pertaining to claim 47, <u>Miller</u> teaches the system of claim 37, wherein said tool comprises a plurality of processing devices, each of which includes an in situ sensor, and

Art Unit: 2823

be executed by the tool.

wherein data from one in situ sensor may be compared with data from another in situ sensor to in real time to compare results from each device.

51. Pertaining to claim 48, Miller teaches a system for controlling a wafer property in a semiconductor processing tool using data collected from an in situ sensor, said system comprising:

means for collecting data with said in situ sensor relating to said wafer property during a process executed according to wafer recipe parameters;

means for adjusting said process by modifying said recipe parameters according to comparisons between said data collected by said in situ sensor relating to said wafer property and results predicted by a process model used to predict wafer outputs; and means for using said data collected by said in situ sensor in a process on a subsequent wafer to

- 52. Pertaining to claim 49, <u>Miller</u> teaches the system of claim 48, wherein said means for adjusting comprises means for increasing or decreasing a processing time.
- 53. Pertaining to claim 50, Miller teaches the system of claim 49, wherein said processing time comprises polishing time.
- Pertaining to claim 51, Miller teaches the system of claim 48, wherein said tool comprises a plurality of processing resources, each of which includes an in situ sensor, and wherein data from one in situ sensor may be forwarded to another processing resource in real time during execution of said process.
- Pertaining to claim 52, <u>Miller</u> teaches the system of claim 48, further comprising means for collecting data from an inline sensor, and

Art Unit: 2823

means for integrating said data collected from said inline sensor with said data collected from said in situ sensor before processing said subsequent wafer.

- 56. Pertaining to claim 53, Miller teaches the system of claim 48, further comprising means for collecting data from a sensor located at an upstream tool, and means for integrating said data collected from said upstream tool with said data collected from said in situ sensor before processing said subsequent wafer.
- Pertaining to claim 54, Miller teaches the system of claim 48, wherein said data collected by said in situ sensor is used for run-to-run control on subsequent wafers processed by said tool.

## Conclusion

- Any inquiry concerning this communication or earlier communications from the examiner should be directed to W. David Coleman whose telephone number is 571-272-1856. The examiner can normally be reached on 9:00 AM-5:00 PM.
- 59. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 571-272-1855. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Art Unit: 2823

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W. David Coleman Primary Examiner Art Unit 2823

**WDC**